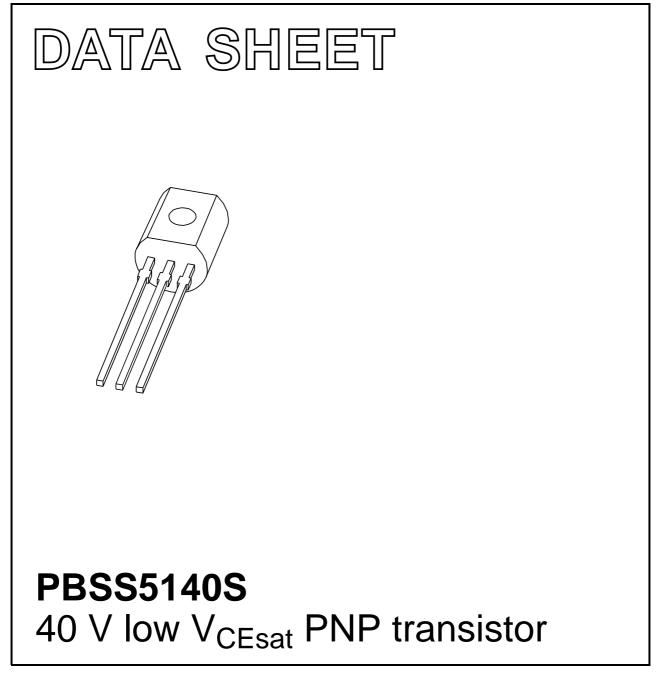
# DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 2001 Nov 15 2004 Aug 13



# **PBSS5140S**

MAX.

-40

-1

-2

<500

2

3

MAM460

UNIT

V

А

A

mΩ

### **FEATURES**

- High power dissipation (830 mW)
- Ultra low collector-emitter saturation voltage
- 1 A continuous current
- · High current switching
- · Improved device reliability due to reduced heat generation.

#### **APPLICATIONS**

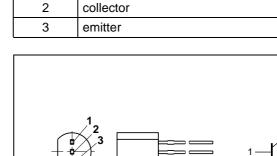
- · Medium power switching and muting
- Linear regulators
- DC/DC converter
- LCD back-lighting
- · Supply line switching circuits
- · Battery driven equipment (mobile phones, video cameras and hand-held devices).

#### DESCRIPTION

PNP low V<sub>CEsat</sub> transistor in a SOT54 plastic package. NPN complement: PBSS4140S.

#### MARKING

TYPE NUMBER	MARKING CODE		
PBSS5140S	S5140S		



QUICK REFERENCE DATA

base

PARAMETER

collector-emitter voltage

collector current (DC)

peak collector current

equivalent on-resistance

DESCRIPTION

SYMBOL

VCEO

 $I_{C}$ 

I<sub>CM</sub>

R<sub>CEsat</sub>

PINNING

PIN

1

Fig.1 Simplified outline (SOT54) and symbol.

### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	_	-40	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-40	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	-5	V
I <sub>C</sub>	collector current (DC)		-	-1	А
I <sub>CM</sub>	peak collector current		-	-2	А
I <sub>BM</sub>	peak base current		-	-1	А
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$ ; note 1	-	830	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

#### Note

1. Device mounted on a printed-circuit board, single sided copper, tinplated and standard footprint.

# PBSS5140S

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	in free air; note 1	150	K/W

#### Note

1. Device mounted on a printed-circuit board, single sided copper, tinplated and standard footprint.

### **CHARACTERISTICS**

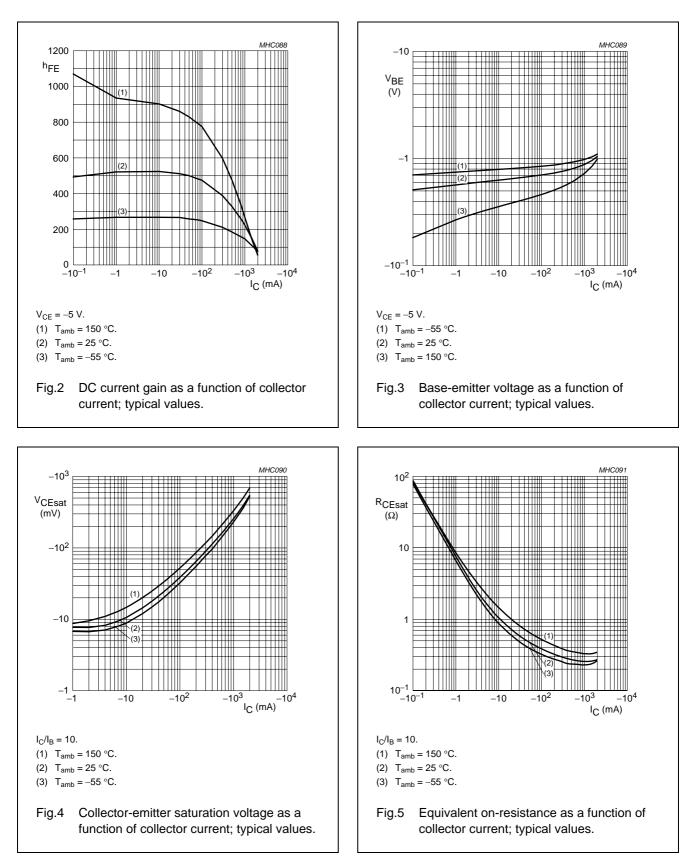
 $T_{amb}$  = 25 °C unless otherwise specified.

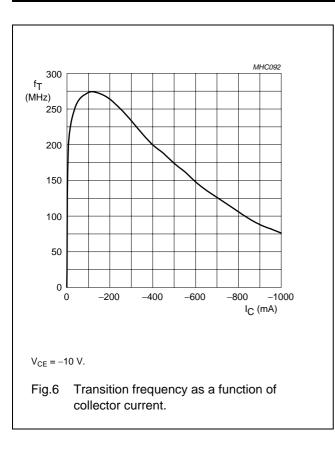
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector-base cut-off	$V_{CB} = -40 \text{ V}; I_C = 0$	_	-	-100	nA
	current	$V_{CB} = -40 \text{ V}; \text{ I}_{C} = 0; \text{ T}_{j} = 150 ^{\circ}\text{C}$	-	-	-50	μA
I <sub>CEO</sub>	collector-emitter cut-off current	$V_{CE} = -30 \text{ V}; \text{ I}_{B} = 0$	-	-	-100	nA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 V; I_{C} = 0$	-	-	-100	nA
h <sub>FE</sub>	DC current gain	$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -1 \text{ mA}$	300	-	-	
		$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -100 \text{ mA}$	300	-	800	
		$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -500 \text{ mA}$	250	-	-	
		$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -1 \text{ A}$	160	-	-	
V <sub>CEsat</sub> collector-emitter saturation voltage	collector-emitter saturation	$I_{\rm C} = -100 \text{ mA}; I_{\rm B} = -1 \text{ mA}$	-	-	-200	mV
	voltage	I <sub>C</sub> = -500 mA; I <sub>B</sub> = -50 mA	-	-	-250	mV
		$I_{\rm C} = -1$ A; $I_{\rm B} = -100$ mA	_	-	-500	mV
R <sub>CEsat</sub>	equivalent on-resistance	$I_{C} = -500 \text{ mA}; I_{B} = -50 \text{ mA}; \text{ note } 1$	_	300	<500	mΩ
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_{\rm C} = -1$ A; $I_{\rm B} = -50$ mA	_	-	-1.1	V
V <sub>BEon</sub>	base-emitter turn-on voltage	$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -1 \text{ A}$	_	_	-1	V
f <sub>T</sub>	transition frequency	$I_{C} = -50 \text{ mA}; V_{CE} = -10 \text{ V};$ f = 100 MHz	150	-	-	MHz
Cc	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = I_e = 0; f = 1 \text{ MHz}$	-	-	12	рF

### Note

1. Pulse test:  $t_p \leq 300~\mu s;~\delta \leq 0.02.$ 

## PBSS5140S

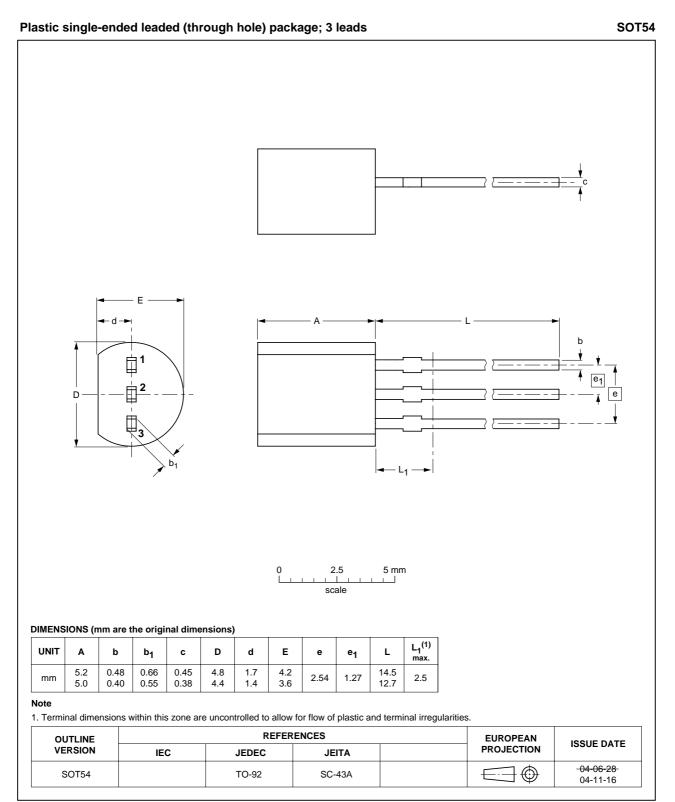




# PBSS5140S

# 40 V low $V_{CEsat}$ PNP transistor

### PACKAGE OUTLINE



**PBSS5140S** 

PBSS5140S

#### DATA SHEET STATUS

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

#### Notes

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# **NXP Semiconductors**

#### **Customer notification**

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

#### **Contact information**

For additional information please visit: http://www.nxp.com For sales offices addresses send e-mail to: salesaddresses@nxp.com

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